NOTES:

1. SUBSTRATE:

Silicon

COATING (APPLY ACROSS COATING APERTURE):
\$1 & \$2: R(AVG) ≤0.5% @ 1250 - 1620

3. WORKING DISTANCE (mm):

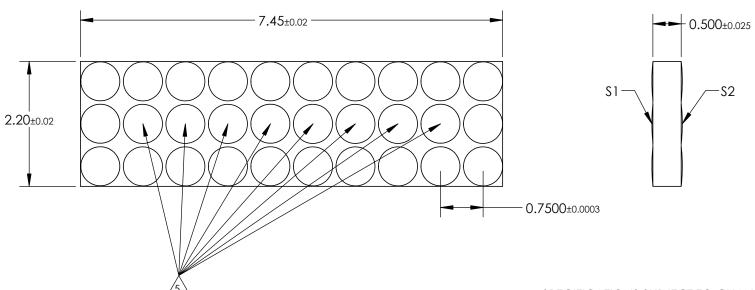
1.1143

4. MODE FIELD DIAMETER (mm):

Source: 0.0104 Target: 0.25

5. ACTIVE LENSES CENTERED ON SUBSTRATE

6. ROHS: COMPLIANT



SPECIFICATIONS SUBJECT TO CHANGE WITHOUT NOTICE DIMENSIONS ARE FOR REFERENCE ONLY

SHEET

1 OF 1

Edmund Optics®

EOD INFORMATION ONLY				<u> </u>	
PARTS TO THIS DRAWING	THIRD ANGLE PROJECTION	THIRD ANGLE PROJECTION		7.45 x 2.20mm, 3.200 ROC, 750µm Pitch, Silicon, 1 x 8 Linear Microlens Array	
	ALL DIMS IN	mm	DWG NO	21179	SHEI

